

Mark Scheme 2825/03

June 2004

Final Mark Scheme 2825/03 June 2004 (i) No. = $1.5/3.0 \times 10^{-10}$ (= 5.0×10^{9}) [1] (ii) Diameter or side of square = 3.0×10^{-10} m / radius = 1.5×10^{-10} m: (1) No. = $1.6 \times 10^{-7} / [\pi \times (1.5 \times 10^{-10})^2]$ (= 2.3×10^{12}) OR $1.6 \times 10^{-7} / [(3.0 \times 10^{-10})^2]$ (= 1.8×10^{12}) (1) [2] (b) e.g. Packing arrangement not taken into account / atoms are not square / circular; (1) Plane of atoms contains grain boundaries: (1) Plane of atoms contains vacancies / impurity atoms: (1) Plane of atoms contains dislocations. (1) max [2] (i) strain = $2.8 \times 10^{-3} / 1.5 = 1.87 \times 10^{-3}$ [1] (ii) stress = E x strain; (1) $= 1.9 \times 10^{11} \times 1.87 \times 10^{-3} = 3.55 \times 10^{8} \text{ Pa}$ $1.9 \times 10^{11} \times 2 \times 10^{-3} = 3.8 \times 10^{8} \text{ Pa}$ (1) [2] (iii) tension = $1.6 \times 10^{-7} \times 3.55 \times 10^8 = 56.8 \text{ N}$ (e.c.f.) OR $1.6 \times 10^{-7} \times 3.8 \times 10^8 = 60.8 \text{ N}$ (e.c.f.) [1] (i) increase in separation = $2.8 \times 10^{-3} / 5.0 \times 10^{9} = 5.6 \times 10^{-13} \text{ m}$ (d) [1] (ii) force causing increased separation = $56.8 / 2.3 \times 10^{12} = 2.5 \times 10^{-11} \text{ N}$ (e.c.f.) $56.8 / 1.8 \times 10^{12} = 3.2 \times 10^{-11} \,\text{N} \, (e.c.f.)$ $56.8/2 \times 10^{12} = 2.8 \times 10^{-11} \text{ N} \text{ (e.c.f.)}$ OR OR 60.8 used instead of 56.8 [1] 2. Allow tolerance of 0.05 in reading logs with consequent variations in answers. (a) (i) $\log \sigma = \log 8.0 \times 10^7 (= 7.90)$ (1)T = 24.5 K Allow +/- 0.5 K (1) [2] (ii) 7 K [1] (i) Use of reading of 8.8 (b) (1) $\sigma_{\text{max}} = 6.31 \times 10^8 \ \Omega^{-1} \, \text{m}^{-1}$ (1) [2] (ii) $\rho_{min} = 1/6.31 \times 10^8 = 1.58 \times 10^9$ (e.c.f.) (1); Ω m. (1) [2]

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3.	(a)	(i) Diagram showing at least a single circle surrounded by 6 equal circles.		[1]
	(b)	(i) Amorphous: No pattern / random arrangement of atoms; Single crystal: a regular array of atoms (extending throughout a body).	(1) (1)	[2]
		(ii) e.g. the silicon used to make a 'chip'; the quartz crystal in a watch or clock; a diamond for appropriate use e.g. cutting.		[1]
	(c)	Metallic glass has an amorphous structure (like glass).		[1]
		is a metal / contains metal atoms; is easy to magnetise in any direction / easy to change the direction of magnetisation / is magnetically soft; minimises energy loss / heat generation in the core; has high resistivity / eddy currents are small; has hysteresis loop of (very) small area; has a high value of magnetic saturation / does not reach magnetic saturation;	(1) (1) (1) (1) (1) (1) (1) max	< [4]
4.	(a)	 (i) Reference to photons and energy; Energy levels in the conduction band of a metal are very closely spaced; The energy of visible light photons is sufficient to raise an electron in the conduction band of the metal to a higher level, (so is absorbed). [Reference to overlapping valence and conduction bands not sufficient.] 	(1) (1) (1) ma	x [2]
		(ii) Energy of visible light photon not sufficient to raise an electron in the valence band of the glass to the conduction band, (so is not absorbed).	(1) (1)	[2]
	(b)	(i) $1.95 \text{ eV} = 1.95 \times 1.6 \times 10^{-19} = 3.12 \times 10^{-19} \text{ J}$	(1)	
		$E = hf / E = hc/\lambda$	(1)	
		$\lambda = hc/E = 6.63 \times 10^{-34} \times 3.0 \times 10^{8} / 3.12 \times 10^{-19} = 6.35 \times 10^{-7} \text{ m} = 635 \text{ nm}$	(1)	[3]
		(ii) Red light is not absorbed by the insulator because its wavelength is greater than 635 nm / Photon energies above this wavelength have insufficient energy		

[1]

to promote electrons in the insulator.

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5.	(a)	(i) $A = 0.0024^2$ $l = 0.043 A$ $v = l/nAe = 0.043 / (7.5 x 10^{20} x 0.0024^2 x 1.6 x 10^{-19}) (= 62.2 m s-1)$	(1) (1)	[2]
		(ii) $V_H = Bvd$ = 0.35 x 62.2 x 0.0024 = 0.052 V (0.050 V if 60 m s ⁻¹ used)	(1) (1)	[2]
		(iii) Lower face of slice marked with X.		[1]
		(iv) Increased thermal energy so n increases; more electrons promoted from valence to conduction band of semiconductor; drift velocity v is reduced because current is constant; [do not accept 'because resistance rises' or 'more atomic vibration'] Hall voltage is smaller because v reduced.	(1) (1)	
			(1) (1) m	ax [3]
	(b)	with narrow dimension of slice perpendicular to field / axis of solenoid; OR two faces of slab without contacts placed perpendicular to field; [Both of above 2 marks can be obtained from a clear sketch] Connect leads from probe to voltmeter / use meter rule to determine position;	(1)	
			(1)	
			(1) (1)	[4]
~		(ii) Connect leads from probe to C.R.O. (with suitable settings) / centre-zero (volt)meter if frequency stated as low		[1]
6.	(a)	(i) Domains randomly orientated.		[1]
		(ii) Domains are aligned (in direction of magnetising field).		[1]
	(b)	(i) 1. Domains already aligned with the (magnetising) field grow due to movement of domain walls. (Other domains shrink.)	(1)	
		2. Domains rotate to align with the (magnetising) field.	(1)	[2]
		(ii) Less steep gradient occurs during stage of domain rotation. Domain rotation takes place less readily than domain growth. Gradient zero when domains are fully aligned.	(1) (1) (1) ma	ax [2]
		(iii) At the Curie temperature saturation flux density becomes zero / magnetisation		
	*.	is lost; There is sufficient thermal energy to disrupt the alignment of domains.	(1) (1)	[2]
	(c)		(1) (1)	[2]
		SD ADARDY CODYARION to book (due to older our older)	(1) (1)	[2]

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8 (a) (i)	Mass	= 0.15 × 5 × 60	1	
		= 45 kg	1	
(ii)	Energy required	= $45 \times 4200 \times (38 - 8)$ Must have temperature difference = 5.67×10^6 J	1	
(b) (i)	Work done	= Force × distance turned (Allow F.d)	1	
		= 80 × 2 π × 0.2	. 1	
		= 100 J		
(ii)	Power produced	= Energy per rev. × Number of rev. per second		
		= 100 × 1.3		
	•	= 130 W	1	
(iii)	Total number of revolutions	= 5.67 × 10 ⁶ / 100		
		= 56700	1	
(iv)	Time for pedalling	= 56700 / 1.3	1	
		= 43615 secs	·	
		= 12.1 hours	1	
c (i) Total resistance in heater circuit = EMF / current Must see some evidence of equation used and physics of problem other than V = IR eg R _{total} = R ₁ + R ₂				
		= 24/5		
		= 4.8 Ω	1	
•	Resistance of element	= 4.8 + 1.2	1	
		= 3.6 Ω		
(ii)	Length or wire	= RA /ρ	1	
		$= 3.6 \times 0.32 \times 10^{-6} / 1.5 \times 10^{-7}$	1	
d	Discussion on energy losses	= 7.68 m Work done against friction in bearings etc	1	
		Power loss from resistance of generator and connecting wires	1	
		Heat radiated from tank	1	

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In one second student outputs 130 J of which only 120 J to generator and only 90J to tank

Thus pedalling time will be longer by factor 130 / 90 giving a new time of 17.5 hours. 2 (Any explained energy loss plus extra time calculations scores up to 2 marks) (Any correct calculation of extra time scores 1 mark)

Maximum 4 marks for question

Up to 3 marks for intelligent discussion (but ignore sound)
Up to 2 marks for calculation

Max 4